

SSC8033GS6

P-Channel Enhancement Mode MOSFET

> Features

VDS	VGS	RDSON Typ.	ID	
201/	1201/	47mR@-10V	4.0	
-30V	±20V	64mR@-4V5	-4A	

> Description

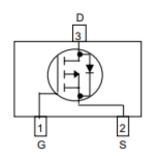
This device is produced with high cell density DMOS trench technology, which is especially used to minimize on-state resistance. This device particularly suits low voltage applications such as portable equipment, power management and other battery powered circuits, and low in-line power dissipation are needed in a very small outline surface mount package.

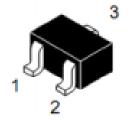
> Applications

- TFT panel power switch
- Portable DVD, DPF
- High side DCDC converter
- High side driver for brushless DC motor

Pin configuration

Top view





SOT23



M05 : Device Code

Marking

> Ordering Information

Device	Package	Shipping		
SSC8033GS6	SOT23	3000/Reel		



➤ **Absolute Maximum Ratings**(T_A=25°C unless otherwise noted)

Symbol	Parameter	Ratings	Unit
V_{DSS}	Drain-to-Source Voltage	-30	V
V _{GSS}	Gate-to-Source Voltage	±20	V
I _D	Continuous Drain Current ^a	-4	Α
I _{DM}	Pulsed Drain Current ^b	-14	Α
P _D	Power Dissipation ^c	1.3	W
P _{DSM}	Power Dissipation ^a	0.74	W
TJ	T _J Operation junction temperature		°C
T _{STG}	Storage temperature range	-55 to 150	°C

➤ Thermal Resistance Ratings(T_A=25°C unless otherwise noted)

Symbol	Parameter	Typical	Maximum	Unit
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance ^a		175	°C/W
Rejc	Junction-to-Case Thermal Resistance		100	C/VV

Note:

- a. The value of $R_{\theta JA}$ is measured with the device mounted on 1 in² FR-4 board with 2oz.copper,in a still air environment with T_A =25°C. The value in any given application depends on the user is specific board design. The current rating is based on the t \leq 10s thermal resistance rating.
- b. Repetitive rating, pulse width limited by junction temperature.
- c. The power dissipation P_D is based on $T_{J(MAX)}$ =150°C, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heat sinking is used.

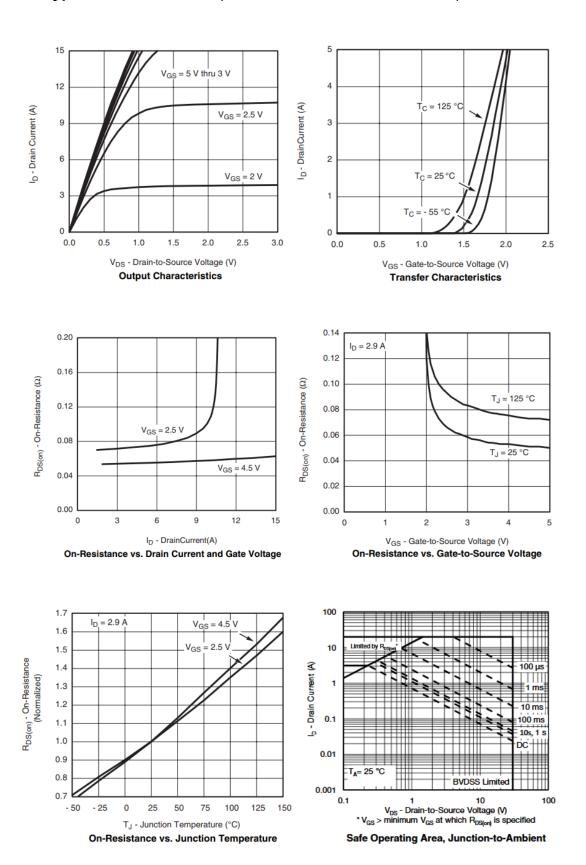


➤ **Electronics Characteristics**(T_A=25 °C unless otherwise noted)

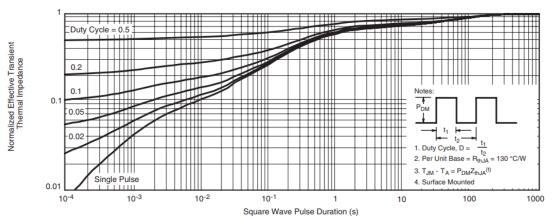
Symbol	Parameter	Test Conditions	Min	Тур.	Max	Unit
V _{(BR)DSS}	Drain-Source Breakdown Voltage	VGS=0V,ID=-250uA	-30			>
V _{GS} (th)	Gate Threshold Voltage	VDS=VGS,ID=-250uA	-1	-1.6	-2	V
R _{DS(on)}	Drain-Source On-	VGS=-10V,ID=-3A		47	70	mR
1 103(011)	Resistance	VGS=-4.5V,ID=-2A		64	90	
I _{DSS}	Zero Gate Voltage Drain Current	VDS=-30V,VGS=0V			-1	uA
I _{GSS}	Gate-Source leak	VGS=±20V,VDS=0V			±100	nA
G _{FS}	Transconductance	VDS=-5V,ID=-2.8A		6		S
V _{SD}	Forward Voltage	VGS=0V,IS=-1A	-0.6	-0.8	-1.3	V
Ciss	Input Capacitance			680		
Coss	Output Capacitance	VDS=-15V , VGS=0V,		72		pF
Crss	Reverse Transfer Capacitance	f=1MHz		58		
$T_{D(ON)}$	Turn-on delay time			20		
Tr	Rise time	VGS=-6V,		13		
T _{D(OFF)}	Turn-off delay time	VGEN=-4.5V, RL=6R, RG=6R,ID=-1.0A		65		ns
Tf Fall time				22		



> Typical Characteristics(T_A=25°C unless otherwise noted)



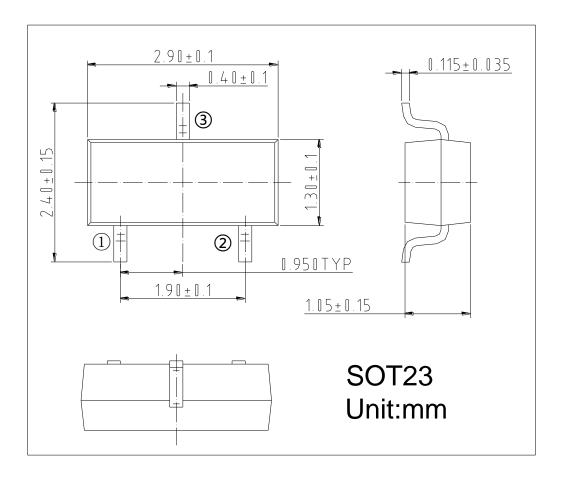




Normalized Thermal Transient Impedance, Junction-to-Ambient

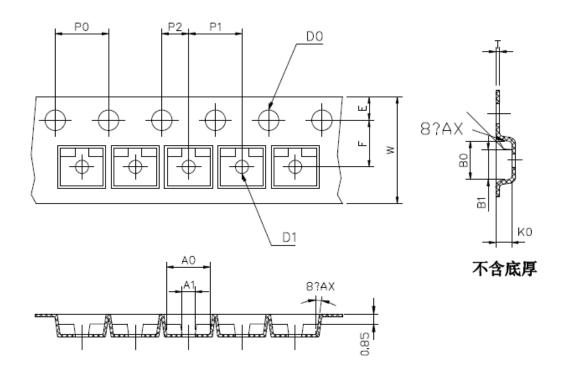


Package Information

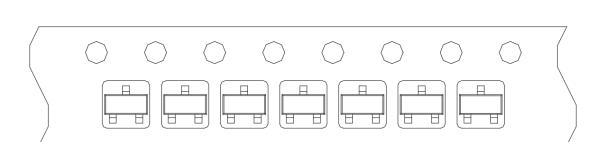




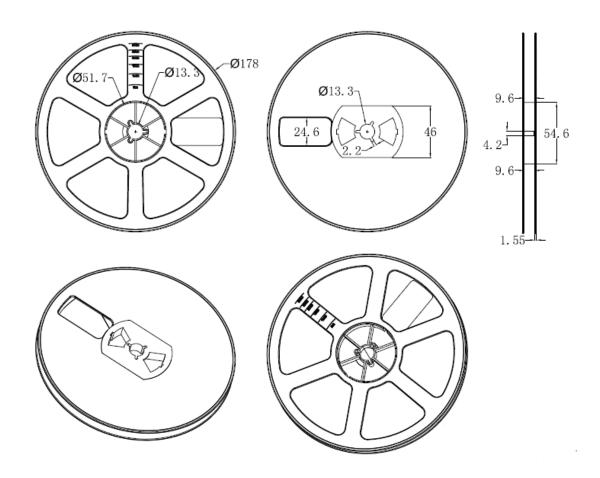
TAPE AND REEL DATA



Symbol	A0	A1	B0	B1	K0	\mathbf{D}_0	\mathbf{D}_1	\mathbf{P}_0	\mathbf{P}_1
Spec	3.15±0.10	1.15±0.10	2.80±0.10	2.15±0.10	1.30±0.10	1.55±0.10	1.10±0.10	4.00±0.10	4.00±0.10
Symbol	W	Е	F	P 2	t	t1	10*P0	4-P0	
Spec	7.95±0.05	1.70±0.05	3.50±0.10	2.00±0.10	0.21±0.02	0.05以上	40.00±0.10	4.00±0.10	







NOTE:

1.材料: PC+PS导电

2:10个链孔的累积公差不能超过0.2MM;

3.250MM带子的扇形不得超过1MM;

4.按照EIA-481-D的要求。



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